## Unconventional superconductivity and m agnetism in $C \, e \! P \, t_3 S \, \dot{i}_4 \, \, _x \, G \, e_x$

E.Bauer,<sup>a;</sup> G.Hilscher,<sup>a</sup> H.Michor,<sup>a</sup> M.Sieberer,<sup>a</sup> E.W.Scheidt,<sup>b</sup> A.Gribanov,<sup>c</sup> Yu.Seropegin,<sup>c</sup> P.Rogl,<sup>d</sup> A.Amato,<sup>e</sup> W.Y.Song,<sup>f;g</sup> J.G.Park,<sup>g</sup> D.T.Adroja,<sup>f</sup> M.Nicklas,<sup>h</sup> G.Sparn,<sup>h</sup> M.Yogi,<sup>i</sup> and Y.Kitaoka<sup>i</sup>

<sup>a</sup> Institut fur Festkorperphysik, Technische Universitat W ien, A -1040 W ien, Austria
 <sup>b</sup> C hem ische Physik und M aterialwissenschaften, Universitat Augsburg, D - 86159 Augsburg, G erm any
 <sup>c</sup> Department of C hem istry, M oscow State University, M oscow, Russia
 <sup>d</sup> Institut fur Physikalische C hem ie, Universitat W ien, A -1090 W ien, Austria
 <sup>e</sup> Laboratory for M uon-Spin Spectroscopy, Paul Scherrer Institute, C H -5232 V illigen PSI, Switzerland

<sup>f</sup> ISIS Facility, Rutherford Appleton Laboratory, Oxon OX11 0QX, England

<sup>g</sup> Departm ent of Physics and Institute of Basic Science, Sungkyunkwan University, Suwon 440-746, Korea

<sup>h</sup>M ax P lanck Institute for C hem ical P hysics of Solids, D -011187 D resden, G erm any <sup>i</sup>D epartm ent of M aterials Science and Technology, O saka U niversity, O saka 560-8531, Japan

## A bstract

CePt<sub>3</sub>Si is a novel ternary compound exhibiting antiferrom agnetic order at  $T_N = 2.2$  K and superconductivity (SC) at  $T_c = 0.75$  K. Large values of  $H_{c2}^{-0} = 8.5$  T/K and  $H_{c2}(0) = 5$  T indicate Cooper pairs formed out of heavy quasiparticles. The mass enhancement originates from K ondo interaction with a characteristic temperature  $T_K = 8$  K.NMR and SR measurements evidence coexistence of SC and long range magnetic order on a microscopic scale. Moreover, CePt<sub>3</sub>Si is the rst heavy fermion SC without an inversion symmetry. This gives rise to a novel type of the NMR relaxation rate 1=T<sub>1</sub> which is very unique and never reported before for other heavy fermion superconductors. Studies of Si/G e substitution allow us to establish a phase diagram.

## Keywords:

 $C \mathrel{\ensuremath{\mathsf{e}}} P \mathrel{\ensuremath{\mathsf{t}}}_3 S \mathrel{\ensuremath{\mathsf{i}}}$  , superconductivity, antiferrom agnetism

Strongly correlated electron system s have been one of the most interesting topics in condensed matter physics. The key importance in such research is undoubtedly the discovery of unexpected features and new phases of metals, interm etallics and oxides at low tem peratures. A mong the topics, quantum phase transitions and related quantum critical phenom ena are of particular importance. Quantum critical uctuations can lead to strong renorm alization of norm alm etallic properties as well as to novel exotic phases emerging from these strongly uctuating environments. One of the most exciting features in this context is the occurrence of SC.

A recently discovered example is tetragonal C  $ePt_3$  Si [1], the rst heavy ferm ion SC without a centre of inversion. This implies that the electron bands are non-degenerate, except along some high-symmetry lines in the Brillouin zone [2]. Reduced degeneracy, how ever, weakens or even suppresses SC. Superconductivity with spin-triplet pairing should require inversion symmetry to obtain the necessary degenerate electron states [3]. Thus, it became a widespread view that a material lacking an inversion center would be an unlikely candidate for spin-triplet pairing [4].

Corresponding author.Tel: + 43 1 58 801 131 60 fax: + 43 1 58 801 131 99

Em ailaddress: bauer@ifp.tuwien.ac.at (E.Bauer,).

Nevertheless, the extreme large value of the upper critical eld  $H_{c2}(0) = 5 T \text{ of } C \text{ ePt}_3 \text{ Si is inconsistent}$  with spin-singlet C ooper-pairs, hinting at some novel features of the SC order parameter.

The aim of this paper is to provide a review of current research on  $C eP t_3 Si$  and to locate the system in the standard generic phase diagram of heavy ferm ion compounds through both substitution and pressure experiments. The paper is organised as follows: A fter a discussion of normal state properties of  $C eP t_3 Si$ , the SC features of  $C eP t_3 Si$  are exam ined before reporting the evolution of magnetism and SC in  $C eP t_3 (Si; Ge)$ .

Norm al state properties

Physical properties of termary CePt<sub>3</sub>Si are dominated by long range magnetic order below  $T_{\rm N} = 2.2~{\rm K}$  and SC below  $T_{\rm c}$  = 0.75 K.Crystal electric eld splitting (CEF) and K ondo interaction substantially modify H und's J = 5=2 ground state of the Ce ion. The response of the system associated with the mutual interplay of these phenom ena will be highlighted below.

Fig.1 displays C<sub>p</sub>=T vs.T ofCePt<sub>3</sub>Si, where C<sub>p</sub> is de ned by the di erence between the  $C_{p}$  (T) data of CePt<sub>3</sub>Siand LaPt<sub>3</sub>Si, i.e. C<sub>m ag</sub> C<sub>p</sub>.Thisplotexhibits three distinct features: i) the SC transition of  $CePt_3SiatT_c = 0.75 K$  (see below), ii) a magnetic 2:2 K and iii) an alm ost logarithtransition at  $T_N$ m ictail of C  $_{\rm p}\mbox{=}T$  above  $T_{\rm N}$  , stretching roughly up to 10 K .W ellabove 10 K, Schottky contributions dom inate in the speci c heat. The integrated entropy up to 20 K is nearly R ln 2, and the entropy of 8.7 J/m ol-K integrated up to 100 K is slightly less than R  $\ln 4 =$ 11:5 J/m ol-K . These results clearly indicate that the ground state of  $Ce^{3+}$  ions is a doublet with the rst excited level above 100 K . The logarithm ic tem perature dependence observed just above the magnetic transition m ay be considered as hint of non-Ferm i liquid behaviour. Therefore, it is a unique observation that non-Ferm i liquid behaviour, magnetic ordering and eventually a SC transition consecutively arises on the sam e sam ple upon low ering tem perature.

In order to analyze in m ore detail the m agnetically ordered region of the system, a m odel by C ontinentino [5] is applied with the following analytic expression for the specic cheat wellbelow  $T_{m ag}$ :

$$C_{m ag} = q {}^{7=2}T^{1=2} \exp( -T)$$

$$1 + \frac{39}{20} \frac{T}{2} + \frac{51}{32} \frac{T}{2} + \frac{51}{32} (1)$$

This expression is based on antiferrom agnetic m agnons with a dispersion relation given by  $! = \frac{p}{2} + D^2 k^2$ , where is the spin-wave gap and D is the spin-wave



Fig. 1. Tem perature dependent m agnetic contribution to the speci c heat, C  $_{\rm p}$  of CePt<sub>3</sub>Siplotted as C  $_{\rm p}$ =T on a logarithm ic tem perature scale. The long-dashed line represents the m agnetic entropy (right axis). The short-dashed line is a guide to the eyes and roughly indicates the non-Ferm i liquid behaviour. The solid line is a t according to Eq. 1 and the dashed-dotted line is a t according to C  $_{\rm p}$  T<sup>3</sup>.

velocity; g / 1=D  $^3$  / 1=  $^3$  and  $\,$  is an e ective m agnetic coupling between Ce ions.A least squares t of Eq.1 to the data below  $T_{\rm N}$  (solid line, Fig.1) reveals

2.7~K, a reasonable gap value with respect to the ordering tem perature. A notherm odel calculation with sim ple antiferrom agnetic spin waves with  $C_{m\ ag}$  /  $T^3$  gives reasonable agreem ent with the data, too. A recent neutron di raction study on CePtsSireveals antiferrom agnetic ordering below  $T_N$  2.2~K with a wave vector k = (0;0;1=2), i.e. doubling of the magnetic unit cell along c-direction [6]. U sing both models, we estimate a Sommerfeld coeccient of 0.41 and 0.39 J/m olK $^2$  for the form er and latterm odels, respectively. These gures are in good agreement with an extrapolation of high eld speci cheat data where SC is suppressed by applying magnetic elds.

Considering K ondo type interactions to be responsible for the signi cant renorm alisation of electrons in  $C\ ePt_3Si$  as evidenced by the Sommerfeld value , the magnetic entropy allows to estimate the K ondo tem – perature  $T_K$ . Taking the results derived in Ref. [7] yields  $T_K$  7.2 K.A second possible estimate  $T_K$  follows from the competition of the RKKY interaction and the K ondo e ect, which leads to a signi cant reduction of the speci cheat jump at  $T=T_N$ . Following the procedure developed in Ref. [8] gives  $T_K$  9 K, in reasonable agreement with the previous estimate.

For better understanding of the m agnetic ground state and expected localized character of C e 4f electrons, inelastic neutron scattering experiments at the HET spectrom eter of ISIS, UK, were carried out. In order to accurately and reliably determ ine m agnetic scattering from the m agnetic m om ents of C e, both C ePt<sub>3</sub>Si and LaPt<sub>3</sub>Si were investigated in powder form under identical conditions. For phonon sub-

traction, we used two well-established methods [9], with almost the same results. Our main nding is that there are strong and clear features from 10 to 30 meV.As shown in Fig.2 ought to be of magnetic



Fig.2.M agnetic scattering obtained at 6.4 K with the incident energy of 35 m eV. The dashed line is for the elastic component with FW HM = 2.4 m eV while the short-dashed line represents the quasi-elastic component with FW HM = 0.8 m eV. The dashed-dotted line is for the sum of two Lorentzian components centered at 13 and 20 m eV with FW HM = 10.0 m eV.

origin as the phonon contributions have been subtracted from the data. In order to explain the data, we used the CEF Ham iltonian for  $Ce^{3+}$  with  $C_{4v}$  point sym metry:  $H_{CEF} = B_2^0 O_2^0 + B_4^0 O_4^0 + B_4^4 O_4^4$ . W ith  $B_2^0 = -0.4972 \text{ meV}$ ,  $B_4^0 = 0.0418 \text{ meV}$ , and  $B_4^4 = 0.2314$ m eV, the observed m agnetic scattering is reasonably well explained (solid line, Fig. 2). Keeping the CEF param eters unchanged, we could also explain the data obtained at 94 K equally well. M oreover, the two CEF excitations centred at 13 and 20 m eV are also consistent with the heat capacity data as discussed above. W e furtherm ore studied low energy excitations using lower incident energy to nd a weak feature around 1.4 meV. The dispersion of that intensity at T = 5 K, particularly around Q =  $0.8 \text{ A}^{-1}$  is a signature for the developm ent of short-ranged m agnetic correlations and explains the anom alous behaviour of the speci c heat above magnetic ordering. At higher tempera-30 K) scattering becom es Q -independent. tures (T This feature is completely absent in non-magnetic LaPt3Si.W e note that a recent inelastic neutron scattering experim ent [6] reported two CEF peaks at 1.0 and 24 m eV. However, our data show that their 2nd excitation is most likely to be mistaken.

Superconducting properties of C eP t<sub>3</sub>Si

Signs of bulk SC of CePt<sub>3</sub>Sibelow  $T_c = 0.75$  K are num erous: zero resistivity, diam agnetic signal in the susceptibility, a jump in the speci c heat and NMR relaxation rate at T<sub>c</sub>.Here, we show in Fig.3 (a) the eld dependent speci c heat at low tem peratures and at various externalm agnetic elds.Som m erfeld coe -



Fig. 3. (a): Tem perature dependent speci c heat C  $_{\rm p}{=}T$  of C ePt<sub>3</sub>Si for various values of applied elds; the dashed line is a T  $^3$  extrapolation of C  $_{\rm p}$  (T) at 0 T. (b): Tem perature dependence of the upper critical eld H  $_{\rm c2}$ . The solid straight line yields H  $_{\rm c2}^0$  8:5T/K; the dashed line is a guide to the eyes.

cient  $_{\rm n}$  0:39 J/m olK  $^2$  of CePt<sub>3</sub>Siat zero eld can be obtained from a careful extrapolation of the norm al state invoking the T  $^3$ -dependence associated with antiferrom agnetic ordering. This extrapolation also satis es the basic requirem ent of an entropy balance between the SC and norm al state regions.

The application of magnetic elds reduces  $T_{c}$ , giving rise to a rather large change of dH  $_{c2}=dT$   $\,$  H  $_{c2}^{0}$ 

8.5~T/K, in good agreement with the conclusion drawn from electrical resistivity [see Fig. 3(b)]. An extrapolation of  $T_{\rm c}$  (H ) towards zero yields  $\rm H_{c2}$  (O) 5~T, well above the Pauli-C logston limiting eld [1]. Furthermore, an estimation of the Sommerfeld coeccient from the high eld data gives  $0.36~J/m~o~K^2$ , in fair agreement with the value obtained from an extrapolation of the normal state in the zero eld data (see Fig. 3). The upturn of  $\rm C_p=T$  at lowest temperatures that gets stronger with increasing magnetic elds is most likely due to the nuclear contribution of  $^{195}\rm Pt$ .

The jump in the speci c heat  $C_p=T_{f_c}$ 0:1J/moK<sup>2</sup>, leads to  $C_p=(_nT_c)$  0.25, which is much smaller than expected from the BCS theory ( $C_p=(T_c)$  1:43). Even using the electronic speci c heat coe cient in the SC state,  $_s$  0:18(1) J/moK<sup>2</sup>, we obtained  $C_p=(_sT_c)$  0:55 that is still below the BCS value.

W e can think of two scenarios that m ay well explain such a substantial reduction of  $C_p = T_c$  with respect to the BCS value; i) spin triplet SC like  $Sr_2RuO_4$  exhibit a sim ilarily reduced m agnitude of  $C_p = (T_c)$  [10] and ii) not all electrons condense into Cooper pairs; thus only a fraction of the carriers mediate the supercurrent. It in plies that electrons responsible for norm al state features, like antiferrom agnetic order,  $\infty$ exist with those form ing the Cooper pairs. In fact, the

nite value of  $_{\rm s}$  0:18 J/m olK<sup>2</sup> provides evidence that even at T = 0 K a signi cant portion of the Ferm i surface is still not involved in the SC condensate.

M icroscopic evidence for the latter conclusion can be found from zero- eld SR spectroscopy data obtained in the magnetic phase below and above  $T_{\rm c}$  in the magnetic phase. (Fig. 4). At tem peratures much above  $T_{\rm N}$ , the SR signal is characteristic of a param – agnetic state with a depolarization solely arising from nuclear moments. Below  $T_{\rm N}$  the SR signal indicates that the full sam ple volum e orders m agnetically. High statistic runs perform ed above and below  $T_{\rm c}$  did not show any change of the magnetic signal, supporting the view of a microscopic coexistence between magnetism and SC . This points to a novel state for SC C e-based



Fig. 4. Zero  $\;$  eld depolarisation rate of  $C \: eP \: t_3Si$  at various tem peratures.

heavy-ferm ion system s at am bient pressure, for which, to date, m agnetism was found to be either absent [11] or strongly competing against SC [12]. The observed coexistence is rem in iscent of the situation observed in  $UPd_2A \downarrow$  [13], where a m odel of two independent electron subsets, localized or itinerant, was proposed in view of sim ilar m icroscopic data [14].

A nother m icroscopic information about the SC state can be obtained from the temperature dependent  $^{195}\text{Pt}$  nuclear spin-relaxation rate  $1=T_1$  [15]. Results are shown as  $(1=T_1T)_{\text{SC}}=(1=T_1T)_{\text{N}}$  vs.  $T=T_c$  plot in Fig.5 for 8.9 and 18.1 M Hz. The relaxation behaviour  $1=T_1T$  of CePt\_3Si is characterized by a kind of the H ebel-Slichter anom aly [16] indicating coherence effects as in conventional BCS SC. The peak height, how ever, is signi cantly smaller than that observed for conventional BCS SC and, additionally, shows no eld dependence at the 8.9 M Hz (H 1 T) and 18.1 M Hz (H 2 T) run.

 $(1=T_1T)$  at H 2 T seems to saturate at low tem - perature, which can be attributed to the presence of vortex cores where the norm al-state region is intro-

duced.1=T<sub>1</sub>T at 8.9 M H z (H 1 T), how ever, continues to decrease down to T = 0.2 K, the low est m easured tem perature. N either an exponential law nor a T<sup>3</sup> behaviour is observed for the data down to T = 0.2 K. Therefore, CePt<sub>3</sub>Siisthe rst HF SC that exhibits a peak in 1=T<sub>1</sub>T just below T<sub>c</sub> and, m oreover, does not follow the T<sup>3</sup> law reported for m ost of the unconventional HF SC (see e.g., Ref. [17] and Refs. therein).



Fig. 5. A plot of  $(1=T_1T)=(1=T_1T)_{T_c}$  vs.  $T=T_c$  at 8.9 MHz (H 1T) and 18.1 MHz (H 2T). The dashed line is for the Balian-W ertham erm odel (BW isotropic triplet SC state) with a value of 2 =k  $_BT_c$  = 4. The dotted line assumes a point-node m odel with 2 =k  $_BT_c$  = 3:6 and the dashed-dotted line represents a t by a line-node gap m odel with 2 =k  $_BT_c$  = 5:1.

To account for the relaxation behavior below  $\ensuremath{\text{T}_{\text{c}}}$ in noncentrosymmetric CePt<sub>3</sub>Si, three models were adopted for a description of the tem perature dependence of 1=T<sub>1</sub> at H 1 T. The dashed line in Fig. 5 represents a taccording to the the Balian-Wertham er model (isotropic spin-triplet SC state) with a value of 2 = $k_B T_c = 3.9$  [18], while the dashed-dotted line is a tusing a line-node model with  $2 = k_B T_c = 5:1$ . The dotted line refers to a point-node model with  $2 = k_B T_c = 3.6$ . The models used, however, failed to give satisfactory description of the observed tem perature dependence of  $1=T_1$  over the entire tem perature range. W hile the line-node m odel gives a reasonable agreem ent with the data at low est tem peratures, the BW model describes reasonably well the data just below  $T_c$ . The peak in  $1=T_1T$  would indicate the presence of an isotropic energy gap, even though a coherence e ect - inherent for the isotropic spin-singlet s-wave pairing state - is absent.

In alm ost all previous studies on either conventional and unconventionalSC, it was assumed that the crystal has an inversion center, which allows separate consideration of the even (spin-singlet) and odd (spin-triplet) components of the SC order parameter. In C ePt<sub>3</sub>Si, how ever, a center of sym m etry is absent. Therefore, the novel relaxation behaviour found below  $T_c$  hints at a possibly new class of a SC state being realized in noncentrosym m etric C ePt<sub>3</sub>Si. G or kov and R ashba [19] dem onstrated that in the absence of inversion sym metry the order parameter becomes a mixture of spin-singlet and spin-triplet com – ponents, which leads, for instance, to the K night shift attaining a non-zero value at T = 0 K. A novel idea with respect to the order parameter of system swithout inversion sym metry was put forward very recently by Saxena and M onthoux [20]. In their model for the case of broken inversion sym metry, the spins might rotate in the momentum space around the surface.

Evolution of magnetism and superconductivity in  $C eP t_3$  (Si;G e)

In order to follow the evolution of physical properties upon Si/Ge substitution, we prepared several alloys. Guinier X-ray powder intensity proles of the alloys from the series CePt<sub>3</sub> (Si  $_x$ Ge<sub>x</sub>) with x = 0.02; 0.03; 0.06; 0.10; 0.15 and 0.20 were all indexed completely on the basis of a primitive tetragonal unit cell, con ming isotypism with the structure type of CePt<sub>3</sub>Si [21] with a random substitution of the Si/Ge atom s in the la sites of space group P 4=m m m . Sm all secondary peaks arise beyond x 0.2 indicating the limit of the CePt<sub>3</sub>B type phase region. Figure 6 show s



Fig. 6. Concentration dependent lattice parameters a, c and unit cellvolum e V of CePt\_3Si\_  $_x\,G\,e_x\,.$ 

the concentration dependent lattice parameters a and c as a function of Si/G e substitution, together with the unit cell volum e. The monotonic increase of both a and c parameters yields a growing unit cell volum e upon doping. The general increase of the unit cell volum es reduces chemical pressure on the Ce atom s leading to a decrease of hybridization.

The tem perature dependent electrical resistivity of  $C eP t_3$  (Si<sub>1 x</sub> G e<sub>x</sub>) is shown for several concentrations x in Fig. 7 for tem peratures below about 4 K. The overall (T) values increase due to increasing substitutional disorder on the 1a site. Sam ples investigated



Fig.7.Low tem perature electrical resistivity for various concentrations x of C ePt<sub>3</sub>Si<sub>1</sub>  $_x$ G ex (sym bols), and tem perature derivative d /dT (lines, right axis).

are characterized by a concentration dependent onset of SC, where the Si/G e substitution suppresses the SC roughly above x = 0.1. At som ewhat elevated tem peratures, (T) exhibits a pronounced curvature which can be taken as a signature for long range m agnetic order, in agreem ent with speci c heat m easurem ents. A m agnetic instability is evidenced from the resistivity data in terms of a d /dT plot (lines, Fig. 7, right axis).d /dT show spronounced anom alies, referring to broadened m agnetic phase transitions; the respective tem peratures increase continuously with increasing G e content.

The magnetic contribution to the speci c heat of  $CePt_3$  (Si<sub>1 x</sub>Ge<sub>x</sub>) is plotted in Fig. 8 as  $C_{mag}=T$  vs. T for several compositions up to x = 0.2 from 1.8 to 20 K.  $C_{mag}$  is derived as in Fig.1 using the measured data of isostructural non-magnetic LaPt<sub>3</sub>Si. A com -



Fig.8.M agnetic contribution to the specific heat C  $_p$  plotted as C  $_p$ =T vs.T for various alloys of C ePt\_3Si\_ xG e\_x .

m on feature in all the data-sets is a mean-eld like anomaly, which is associated with magnetic order of the cerium sublattice.  $T_{\rm N}$  rises with increasing G e content and, simultaneously, the phase transitions appear to be broadened, in agreement with the observation

m ade from d /dT.W hile for x = 0, the logarithm ic behaviour well above  $T_N$  is quite pronounced and obvious, its temperature range becomes narrower with increasing G e content as a consequence of increasing m agnetic interactions, driving a m agnetic instability atm uch higher temperatures. The double-peak feature for x = 0.2 is m ost likely due to a secondary phase as indicated by our XRD analysis.

The phase diagram shown in Fig.9 sum marizes characteristic tem peratures deduced for C ePt<sub>3</sub> (Si<sub>1</sub> <sub>x</sub>Ge<sub>x</sub>) at am bient pressure, as well as data derived from resistivity studies on C ePt<sub>3</sub>Siunderhydrostatic pressure up to about 15 kbar [22]. In order to make comparison between substitution and pressure, M umaghan's equation of state is adopted, with a bulk m odulus B<sub>0</sub> = 1000 kbar. Pressure of 15 kbarcorresponds then with a reduction of the unit cell volume of about 1 %. The



Fig.9.Phase diagram of CePt<sub>3</sub> (Si<sub>1 x</sub>Ge<sub>x</sub>).

phase diagram thus deduced resembles very well those characteristics, which determ ine the standard generic phase diagram associated with a quantum phase transition. The increase of the unit cell volume by the Si/Ge substitution is, in a rst-order approximation, responsible for a decrease of hybridisation. This has two consequences: i) the K ondo interaction decreases and ii) magnetic interaction strengthens, causing the observed increase of the magnetic transition temperature. Concom itantly, the SC transition temperature becom es suppressed and nally, SC vanishes beyond x > 0:1. Increasing hydrostatic pressure is responsible for a decrease of both  $T_{\rm N}\,$  and  $T_{\rm c}$  . Temary C eP  $t_3\,S$  ithus appears to be, by chance, situated at the maximum position of the \superconducting dom e".W hether or not this SC dome is constrained within the magnetic phase is still unknown. Depending on the particular choice of B<sub>0</sub>, i.e. sm aller or larger than  $B_0 = 1000$  kbar the volum e below  $V = V_0 = 1$  becomes strechted or narrower. In any case,  $T_{\rm c}^{\,\rm m\,ax}$  is well below the magnetic phase line, being a signature that C ooper pairing m ay be mediated by magnetic uctuations rather than by the standard phonon mechanism .

W e sum m arize that non-centrosym m etric C ePt<sub>3</sub>Si is a heavy ferm ion SC w ith  $T_{\rm c}$  = 0:75 K that orders m agnetically at  $T_{\rm N}$  = 2.2 K. The NM R relaxation rate 1=T<sub>1</sub> shows unexpected features which were found before neither in conventional nor in heavy ferm ion SC, indicative of very unusual shapes of the SC order parameter. In fact, a num ber of theoretical scenarios support these observations. The Si/G e substitution sim – ply drives a volum e expansion, thus m agnetism is stabilized and SC nally ceases to exist.

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## References

- [1] E.Bauer et al, Phys. Rev. Lett. 92 (2004) 027003.
- [2] K.V.Sam okhin et al., Phys.Rev.B 69 (2004) 094514.
- [3] P.W .Anderson, Phys. Rev. B 30 (1984) 4000.
- [4] P.Frigeri et al., Phys. Rev. Lett. 92 (2004) 097001.
- [5] M. Continentino et al., Phys. Rev. B 64 (2001) 012404.
- [6] N.M etokietal., J.Phys.:Cond.M at.16 (2004) L207.
- [7] H.U. Desgranges and K.D. Schotte, Phys. Lett. A 91 (1982) 240.
- [8] M.Besnus et al., J.M agn.M agn.M at. 104 107 (1992) 1385.
- [9] D.T.Adroja et al., Phys. Rev. B68 (2003) 094425.
- [10] A P.M akenzie and Y.M aeno, Rev.M od.P hys.75,(2003)  $_{657}$  .
- [11] C.Petrovic et al., Europhys.Lett. 53 (2001) 354.
- [12] G M . Luke et al., Phys. Rev. Lett. 73 (1994) 1853.
- [13] R.Feyerherm et al., Phys.Rev.B 56 (1997) 699.
- [14] R.Caspary et al., Phys. Rev. Lett. 71 (1993) 2146.
- [15] M .Yogietal, Phys.Rev.Lett. (2004) in press.
- [16] L.C.Hebeland C.P.Slichter, Phys. Rev. 107 (1957) 901.
- [17] H. Tou et al., J. Phys. Soc. Jpn. 64 (2003) 725.
- [18] R.Balian and N.R.W ertham er, Phys. Rev. 131 (1963) 1553.
- [19] L P.G orkov and E.I.R ashba, Phys.Rev.Lett.87 (2001) 037004.
- [20] S.S.Saxena and P.M onthoux, Nature 427 (2004) 799.
- [21] O . Sologub et al., J. A lloys C om pounds 337 (2002) 10.
- [22] M . N icklas, et al., to be presented at this conference.